

Fast CMOS 16-Bit Registers (3-State)

**Features**

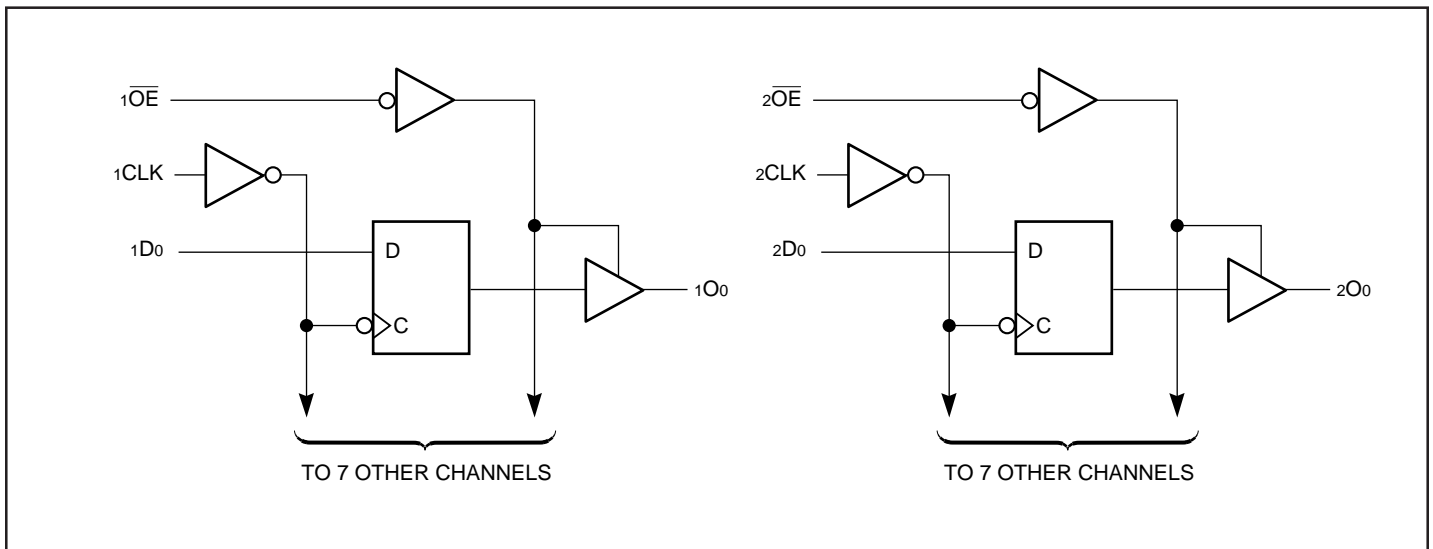
- High-speed, low power device with high current drive.
- $V_{CC} = 5V \pm 10\%$
- Hysteresis on all inputs
- Supports Hot Insertion
- Balanced output drivers:  $\pm 24$  mA
- Reduced system switching noise
- Typical  $V_{OLP}$  (Output Ground Bounce)  $< 0.6V$  at  $V_{CC} = 5V, T_A = 25^\circ C$
- Packages available:
  - 48-pin 240 mil wide plastic TSSOP (A)
  - 48-pin 300 mil wide plastic SSOP (V)

**Description**

Pericom Semiconductor's PI74FCT162374T is a 16-bit octal registers designed with 16 D-type flip-flops with a buffered common clock and 3-state outputs. The Output Enable ( $\overline{xOE}$ ) and clock ( $xCLK$ ) controls are organized to operate as two 8-bit registers or one 16-bit register. When  $\overline{OE}$  is HIGH, the outputs are in the high impedance state. Input data meeting the setup and hold time requirements of the D inputs is transferred to the O outputs on the LOW-to-HIGH transition of the clock input.

The PI74FCT162374T has  $\pm 24$  mA balanced output drivers. It is designed with current limiting resistors at its outputs to control the output edge rate resulting in lower ground bounce and undershoot. This eliminates the need for external terminating resistors for most interface applications.

**Block Diagram**



### Pin Description

Pin Name	Description
$\overline{xOE}$	3-State Output Enable Inputs (Active LOW)
xCLK	Clock Inputs
xDx	Inputs <sup>(1)</sup>
xOx	3-State Outputs
GND	Ground
Vcc	Power

**Note:** 1. For the PI74FCT162H374T, these pins have “Bus Hold.”  
All other pins are standard, outputs, or I/Os.

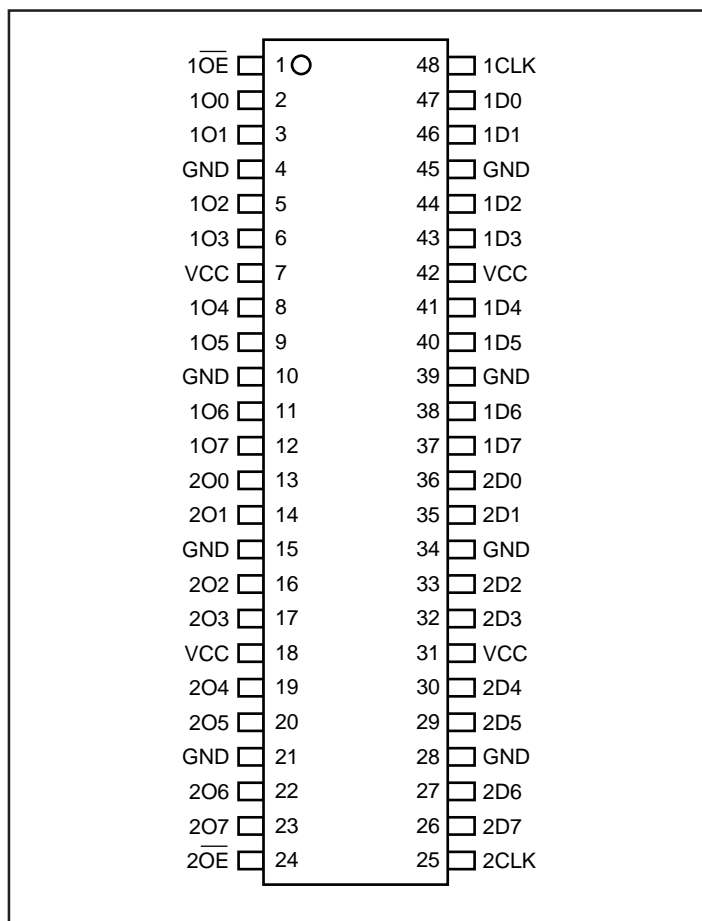
### Truth Table<sup>(1)</sup>

Function	Inputs			Outputs
	xDx	xCLK	$\overline{xOE}$	xOx
High-Z	X	L	H	Z
	X	H	H	Z
Load Register	L	↑	L	L
	H	↑	L	H
	L	↑	H	Z
	H	↑	H	Z

**Note:**

- H = High Voltage Level  
L = Low Voltage Level  
X = Don't Care  
Z = High Impedance  
↑ = LOW-to-HIGH transition

### Pin Configuration



## Maximum Ratings

(Above which the useful life may be impaired. For user guidelines, not tested.)

Storage Temperature .....	-65°C to +150°C
Ambient Temperature with Power Applied .....	-40°C to +85°C
Supply Voltage to Ground Potential (Inputs & Vcc Only) .....	-0.5V to +7.0V
Supply Voltage to Ground Potential (Outputs & D/O Only) .....	-0.5V to +7.0V
DC Input Voltage .....	-0.5V to +7.0V
DC Output Current .....	120 mA
Power Dissipation .....	1.0W

### Note:

Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

## DC Electrical Characteristics (Over the Operating Range, TA = -40°C to +85°C, VCC = 5.0V ± 10%)

Parameters	Description	Test Conditions <sup>(1)</sup>		Min.	Typ <sup>(2)</sup>	Max.	Units
V <sub>IH</sub>	Input HIGH Voltage	Guaranteed Logic HIGH Level		2.0			V
V <sub>IL</sub>	Input LOW Voltage	Guaranteed Logic LOW Level				0.8	V
I <sub>IH</sub>	Input HIGH Current	Standard Input, V <sub>CC</sub> = Max.	V <sub>IN</sub> = V <sub>CC</sub>			1	μA
I <sub>IH</sub>	Input HIGH Current	Standard I/O, V <sub>CC</sub> = Max.	V <sub>IN</sub> = V <sub>CC</sub>			1	μA
I <sub>IH</sub>	Input HIGH Current	Bus Hold Input <sup>(4)</sup> , V <sub>CC</sub> = Max.	V <sub>IN</sub> = V <sub>CC</sub>			±100	μA
I <sub>IH</sub>	Input HIGH Current	Bus Hold I/O <sup>(4)</sup> , V <sub>CC</sub> = Max.	V <sub>IN</sub> = V <sub>CC</sub>			±100	μA
I <sub>IL</sub>	Input LOW Current	Standard Input, V <sub>CC</sub> = Min.	V <sub>IN</sub> = GND			-1	μA
I <sub>IL</sub>	Input LOW Current	Standard I/O, V <sub>CC</sub> = Min.	V <sub>IN</sub> = GND			-1	μA
I <sub>IL</sub>	Input LOW Current	Bus Hold Input <sup>(4)</sup> , V <sub>CC</sub> = Min.	V <sub>IN</sub> = GND			±100	μA
I <sub>IL</sub>	Input LOW Current	Bus Hold I/O <sup>(4)</sup> , V <sub>CC</sub> = Min.	V <sub>IN</sub> = GND			±100	μA
I <sub>BHH</sub>	Bus Hold	Bus Hold Input <sup>(4)</sup> , V <sub>CC</sub> = Min.	V <sub>IN</sub> = 2.0V	-50			μA
I <sub>BHL</sub>	Sustain Current		V <sub>IN</sub> = 0.8V	+50			
I <sub>OZH</sub> <sup>(5)</sup>	High Impedance	V <sub>CC</sub> = Max.	V <sub>OUT</sub> = 2.7V			1	μA
I <sub>OZL</sub> <sup>(5)</sup>	Output Current	V <sub>CC</sub> = Max.	V <sub>OUT</sub> = 0.5V			-1	μA
V <sub>IK</sub>	Clamp Diode Voltage	V <sub>CC</sub> = Min., I <sub>IN</sub> = -18 mA			-0.7	-1.2	V
I <sub>OS</sub>	Short Circuit Current	V <sub>CC</sub> = Max. <sup>(3)</sup> , V <sub>OUT</sub> = GND		-80	-140	-200	mA
I <sub>O</sub>	Output Drive Current	V <sub>CC</sub> = Max. <sup>(3)</sup> , V <sub>OUT</sub> = 2.5V		-50		-180	mA
V <sub>H</sub>	Input Hysteresis				100		mV

### Notes:

1. For Max. or Min. conditions, use appropriate value specified under Electrical Characteristics for the applicable device type.
2. Typical values are at V<sub>CC</sub> = 5.0V, +25°C ambient and maximum loading.
3. Not more than one output should be shorted at one time. Duration of the test should not exceed one second.
4. Pins with Bus Hold are identified in the pin description.
5. This specification does not apply to bi-directional functionalities with Bus Hold.

**Power Supply Characteristics**

Parameters	Description	Test Conditions <sup>(1)</sup>		Min.	Typ <sup>(2)</sup>	Max.	Units
I <sub>CC</sub>	Quiescent Power Supply Current	V <sub>CC</sub> = Max.	V <sub>IN</sub> = GND or V <sub>CC</sub>		0.1	500	μA
ΔI <sub>CC</sub>	Supply Current per Input @ TTL HIGH	V <sub>CC</sub> = Max.	V <sub>IN</sub> = 3.4V <sup>(3)</sup>		0.5	1.5	mA
I <sub>CCD</sub>	Supply Current per Input per MHz <sup>(4)</sup>	V <sub>CC</sub> = Max., Outputs Open x $\overline{OE}$ = GND One Bit Toggling 50% Duty Cycle	V <sub>IN</sub> = V <sub>CC</sub> V <sub>IN</sub> = GND		60	100	μA/ MHz
I <sub>C</sub>	Total Power Supply Current <sup>(6)</sup>	V <sub>CC</sub> = Max., Outputs Open f <sub>CP</sub> = 10 MHz 50% Duty Cycle x $\overline{OE}$ = GND fi = 5 MHz 50% Duty Cycle One Bit Toggling	V <sub>IN</sub> = V <sub>CC</sub> V <sub>IN</sub> = GND		0.6	1.5 <sup>(5)</sup>	mA
			V <sub>IN</sub> = 3.4V V <sub>IN</sub> = GND		1.1	3.0 <sup>(5)</sup>	
		V <sub>CC</sub> = Max., Outputs Open f <sub>CP</sub> = 10 MHz 50% Duty Cycle x $\overline{OE}$ = GND 16 Bits Toggling fi = 2.5 MHz 50% Duty Cycle	V <sub>IN</sub> = V <sub>CC</sub> V <sub>IN</sub> = GND		3.0	5.5 <sup>(5)</sup>	
			V <sub>IN</sub> = 3.4V V <sub>IN</sub> = GND		7.5	19.0 <sup>(5)</sup>	

**Notes:**

- For Max. or Min. conditions, use appropriate value specified under Electrical Characteristics for the applicable device.
- Typical values are at V<sub>CC</sub> = 5.0V, +25°C ambient.
- Per TTL driven input (V<sub>IN</sub> = 3.4V); all other inputs at V<sub>CC</sub> or GND.
- This parameter is not directly testable, but is derived for use in Total Power Supply Calculations.
- Values for these conditions are examples of the I<sub>CC</sub> formula. These limits are guaranteed but not tested.

$$I_C = I_{\text{QUIESCENT}} + I_{\text{INPUTS}} + I_{\text{DYNAMIC}}$$

$$I_C = I_{CC} + \Delta I_{CC} D_H N_T + I_{CCD} (f_{CP}/2 + f_i N_i)$$

I<sub>CC</sub> = Quiescent Current

ΔI<sub>CC</sub> = Power Supply Current for a TTL High Input (V<sub>IN</sub> = 3.4V)

D<sub>H</sub> = Duty Cycle for TTL Inputs High

N<sub>T</sub> = Number of TTL Inputs at D<sub>H</sub>

I<sub>CCD</sub> = Dynamic Current Caused by an Input Transition Pair (HLH or LHL)

f<sub>CP</sub> = Clock Frequency for Register Devices (Zero for Non-Register Devices)

f<sub>i</sub> = Input Frequency

N<sub>i</sub> = Number of Inputs at f<sub>i</sub>

All currents are in milliamps and all frequencies are in megahertz.

**Output Drive Characteristics** (Over the Operating Range)

Parameters	Description	Test Conditions <sup>(1)</sup>		Min.	Typ <sup>(2)</sup>	Max.	Units
V <sub>OH</sub>	Output HIGH Voltage	V <sub>CC</sub> = Min., V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -24.0 mA	2.4	3.3		V
V <sub>OL</sub>	Output LOW Voltage	V <sub>CC</sub> = Min., V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 24 mA		0.3	0.55	V
I <sub>ODL</sub>	Output LOW Current	V <sub>CC</sub> = 5V, V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> , V <sub>OUT</sub> = 1.5V <sup>(3)</sup>		60	115	150	mA
I <sub>ODH</sub>	Output HIGH Current	V <sub>CC</sub> = 5V, V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> , V <sub>OUT</sub> = 1.5V <sup>(3)</sup>		-60	-115	-150	mA

**Capacitance** (T<sub>A</sub> = 25°C, f = 1 MHz)

Parameters <sup>(4)</sup>	Description	Test Conditions	Typ	Max.	Units
C <sub>IN</sub>	Input Capacitance	V <sub>IN</sub> = 0V	4.5	6	pF
C <sub>OUT</sub>	Output Capacitance	V <sub>OUT</sub> = 0V	5.5	8	pF

**Notes:**

1. For Max. or Min. conditions, use appropriate value specified under Electrical Characteristics for the applicable device type.
2. Typical values are at V<sub>CC</sub> = 5.0V, +25°C ambient and maximum loading.
3. Not more than one output should be shorted at one time. Duration of the test should not exceed one second.
4. This parameter is determined by device characterization but is not production tested.

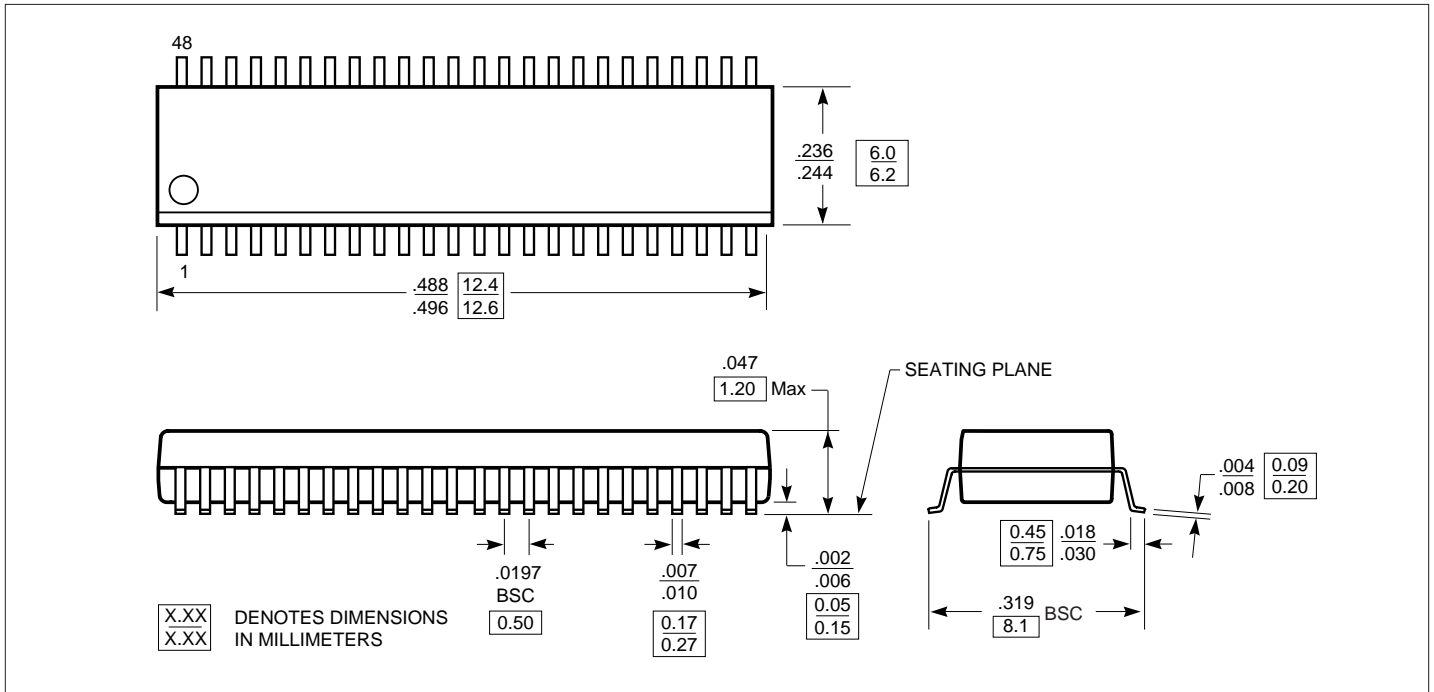
**Switching Characteristics over Operating Range**

Parameters	Description	Conditions <sup>(1)</sup>	162374T		162374AT		162374CT		Unit
			Com.		Com.		Com.		
			Min	Max	Min	Max	Min	Max	
t <sub>PLH</sub>	Propagation Delay	C <sub>L</sub> = 50 pF R <sub>L</sub> = 500Ω	2.0	10.0	2.0	6.5	2.0	5.2	ns
t <sub>PHL</sub>	xCLKx to xOx								
t <sub>PZH</sub>	Output Enable Time		1.5	12.5	1.5	6.5	1.5	5.5	ns
t <sub>PZL</sub>	xOE to xOx								
t <sub>PHZ</sub>	Output Disable Time <sup>(3)</sup>		1.5	8.0	1.5	5.5	1.5	5.0	ns
t <sub>PLZ</sub>	xOE to xOx								
t <sub>SU</sub>	Setup Time HIGH or LOW, xDx to xCLK		2.0	—	2.0	—	2.0	—	ns
t <sub>H</sub>	Hold Time HIGH or LOW, xDx to xCLK		1.5	—	1.5	—	1.5	—	ns
t <sub>w</sub>	xCLK Pulse Width HIGH or LOW <sup>(3)</sup>	7.0	—	5.0	—	5.0	—	ns	
t <sub>SK(0)</sub>	Output Skew <sup>(4)</sup>	—	0.5	—	0.5	—	0.5	ns	

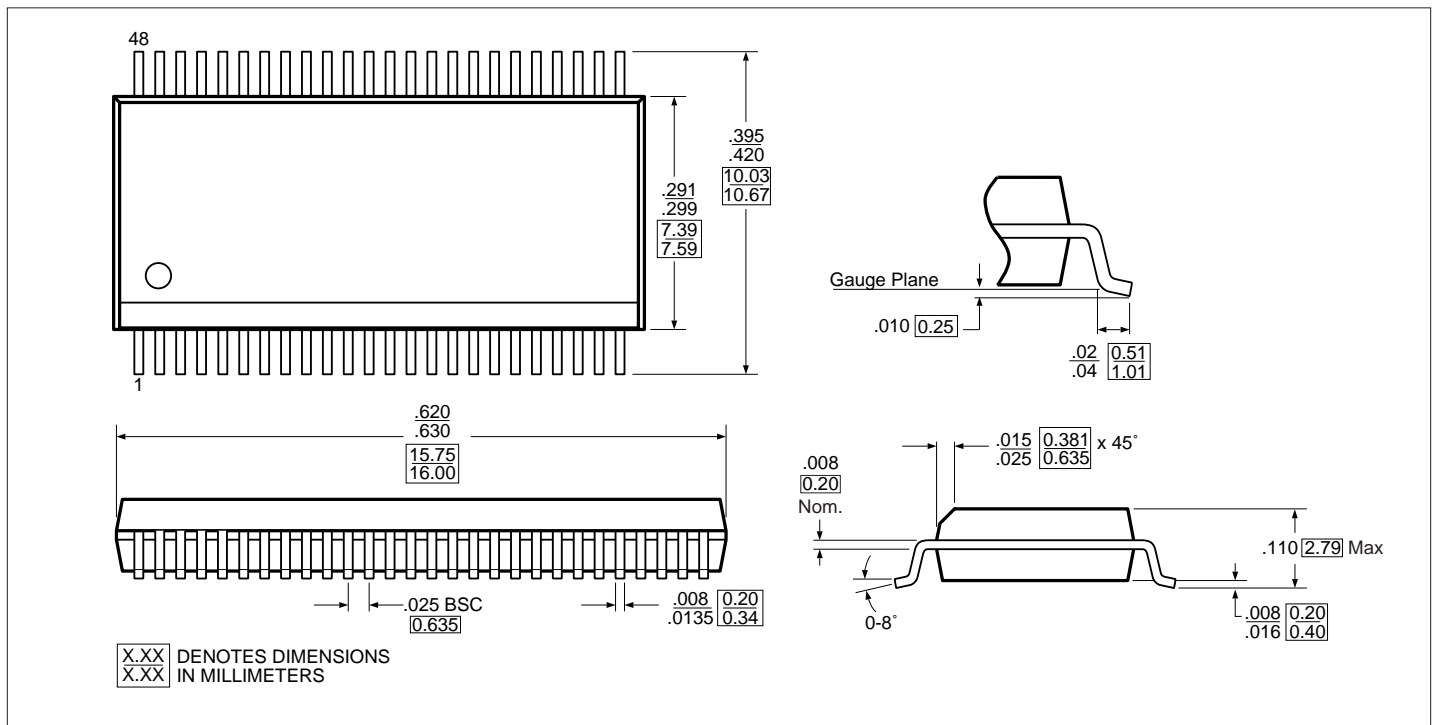
**Notes:**

1. See test circuit and wave forms.
2. Minimum limits are guaranteed but not tested on Propagation Delays.
3. This parameter is guaranteed but not production tested.
4. Skew between any two outputs, of the same package, switching in the same direction. This parameter is guaranteed by design.

**Packaging Mechanical: 48-pin 240-mil wide plastic TSSOP (A)**



**Packaging Mechanical: 48-pin 300-mil wide plastic SSOP (V)**



**Ordering Information**

Ordering Code	Package Code	Speed Grade	Package Type
PI74FCT162373TA	A	Blank	48-pin TSSOP
PI74FCT162373TV	V	Blank	48-pin SSOP
PI74FCT162373ATA	A	A	48-pin TSSOP
PI74FCT162373ATV	V	A	48-pin SSOP
PI74FCT162373CTA	A	C	48-pin TSSOP
PI74FCT162373CTV	V	C	48-pin SSOP

**Notes:**

1. Thermal characteristics can be found on the company web site at [www.pericom.com/packaging/](http://www.pericom.com/packaging/)